



# **PRODUCT DATASHEET**



- EMC SMD Top View
- Infrared (IR) 940nm



# 3838 1.9t Series



AEC-Q102

# **FEATURES:**

- Package: Black Ceramic Dual Junction with Asymmetric Lens
- Forward Current: 1000~1500mA
- Pulse Forward Current (max.): 5A
- Forward Voltage (typ.): 3.1V .
- Radiant Power (typ.): 1400mW@1A; 2100mW@1.5A •
- Radiant Intensity (typ.): 430mW/sr@1A; 640mW/sr@1.5A
- Colour: Infrared (IR) •
- Peak Wavelength (typ.): 940nm •
- Viewing Angle: X:150° / Y: 90°
- Operating Temperature: -40~+125°C
- Storage Temperature: -40~+125°C .
  - **Grouping Parameters:** 
    - \_ **Forward Voltage**
    - **Radiant Power**
    - Peak Wavelength
- Soldering Methods: Reflow
- MSL Level: MSL2 according to J-STD020
- Corrosion Robustness Class: 3B
- Packing: 12mm tape with max.800/reel, ø178mm (7")



NOF60S80BF

## 3838 1.9t Series

## **APPLICATIONS:**

- Automotive .
- Security Camera
- Motion Detection
- **Night Viewer** •
- Surveillance •
- Data Communication •
- **Facial Recognition**
- **Gesture Recognition**



# CHARACTERISTICS:

Parameter	Symbol	Ratings	Unit
DC Forward Current	lf	1500	mA
Pulse Forward Current	Ipf	5	А
Power Consumption	P <sub>tot</sub>	5.5	W
Reverse Voltage	V <sub>R</sub>	5	V
Reverse Current @5V	IR	10	μΑ
Junction Temperature	Tj	145	°C
Thermal Resistance Junction to Solder Point	R <sub>th</sub>	typ. 4.5; max. 9	K/W
Electrostatic Discharge (HBM: MIL-STD-883 C 2)	ESD	2	kV
Operating Temperature	T <sub>OPR</sub>	-40~+125	°C
Storage Temperature	T <sub>STG</sub>	-40~+125	°C
Soldering Temperature	T <sub>SOL</sub>	260	°C

### Absolute Maximum Characteristics (T<sub>a</sub>=25°C)



Parameter		Symbol	Values		Unit	Test		
		Symbol	Min.	Тур.	Max.	Onit	Condition	
			2.8	3.1	3.6		I <sub>F</sub> =1A	
			2.0	5.1	5.0		t <sub>p</sub> =100μs	
Forward Voltage		VF	2.85 3.25	3.25	3.65	v	I <sub>F</sub> =1.5A	
Forward voltage		VF	2.65	5.25		v	t <sub>p</sub> =100μs	
				4.4	5.0		I <sub>F</sub> =5A	
				4.4	5.0		t <sub>p</sub> =100µs	
			1200	1400	1600		IF=1A	
Radiant Power		Φe	1200	1400	1000	mW	t <sub>p</sub> =100µs	
Rauidiit POWEI		Ψe	1900	2100	2300	11100	I⊧=1.5A	
			1900	2100	2500		t <sub>p</sub> =100μs	
		l <sub>e</sub> -	330	430	530		IF=1A	
Radiant Intensity						mW/sr	t <sub>p</sub> =100μs	
Radiane interisity		ie.	540 640	740	11100/51	I <sub>F</sub> =1.5A		
			540	040	740		t <sub>p</sub> =100μs	
Peak Wavelength		Λp		940		nm	I <sub>F</sub> =1A	
Spectral Bandwidth		Δλ		45		nm	IF=1A	
Viewing Angle	х	×		150				
			130		deg	I⊧=1A		
Viewing Aligie		201/2		90		ucg	11-17	

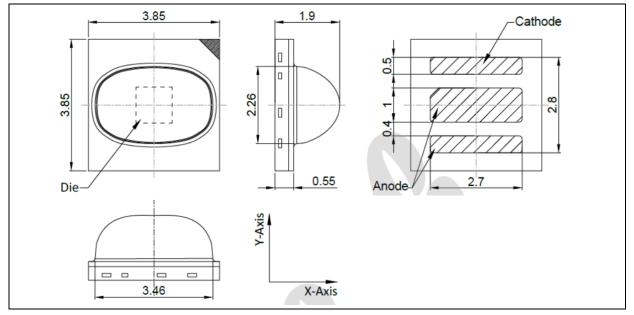
## Electrical & Optical Characteristics (T<sub>a</sub>=25°C, I<sub>F</sub>=1A, t<sub>p</sub>=10ms)

1. Radiant Power (P\_0)  $\pm 10\%$ , Forward Voltage (V\_F)  $\pm 0.1V$ , Viewing angle( $2\theta_{1/2}$ )  $\pm 10^{\circ}$ 



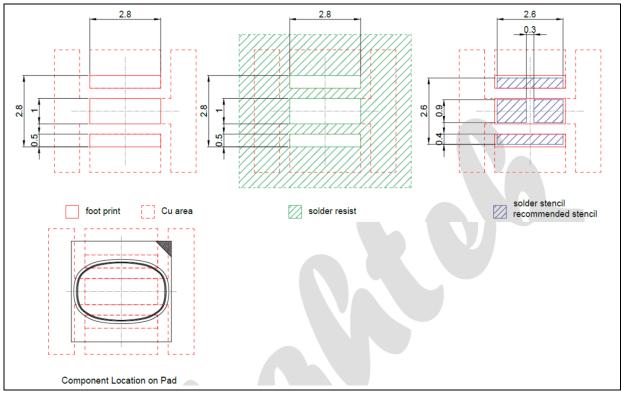
# **OUTLINE DIMENSION:**

### Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm, unless otherwise noted.

#### Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



## **BINNING GROUPS:**

## Forward Voltage Classifications (I<sub>F</sub>=1A; t<sub>p</sub>=10ms):

Code	Min.	Max.	Unit
KN	2.8	3.6	V

### Radiant Power Classifications (I<sub>F</sub>=1A; t<sub>p</sub>=10ms):

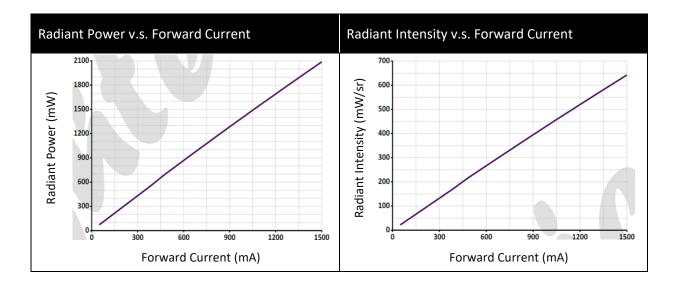
Code	Min.	Max.	Unit	
PB2A	1200	1400		
PB4A	1400	1600	mW	

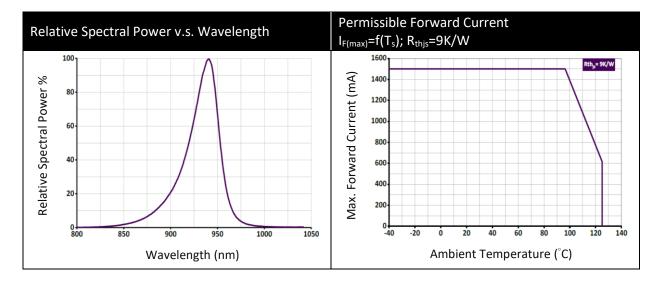
## Peak Wavelength Classifications ( $I_F=1A$ ; $t_p=10ms$ ):

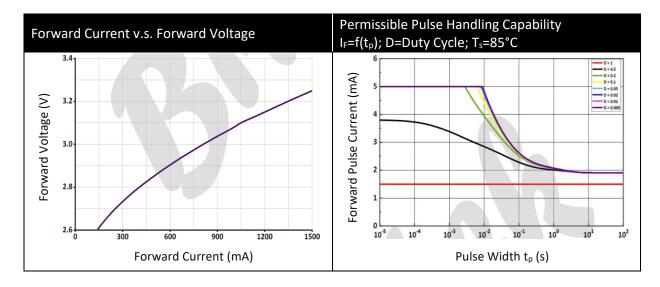
Code	Min.	Max.	Unit
F1	930	950	nm



# **ELECTRO-OPTICAL CHARACTERISTICS:**

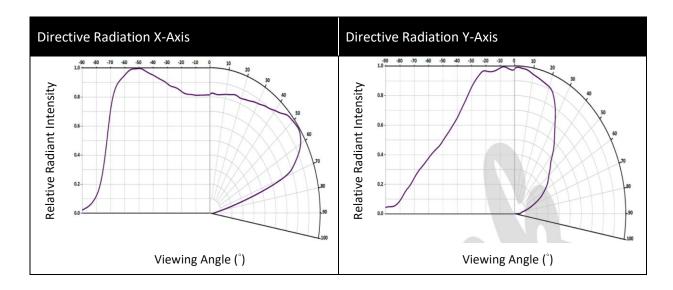






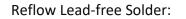


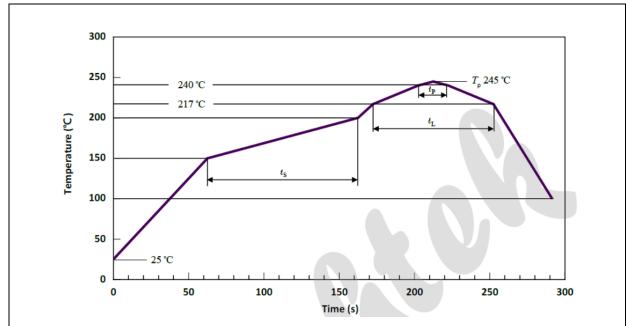
# **ELECTRO-OPTICAL CHARACTERISTICS:**





# **RECOMMENDED SOLDERING PROFILE:**





Profile Feature	Symbol Pb		Free (SnAgCu) Assembly		
		Minimum Recommendation		Maximum	
Ramp-up rate to preheat 25 °C to 150 °C			2	3	K/s
Time ts Tsmin to Tsmax	ts	60	100	120	s
Ramp-up rate to peak T <sub>Smax</sub> to T <sub>P</sub>			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	tL		80	100	s
Peak temperature	Тр		245	260	°C
Time within 5 °C of the specified peak temperature TP - 5 K	Тр	10	20	30	s
Ramp-down Rate T <sub>P</sub> to 100 °C			3	4	K/s
Time 25 °C to T <sub>P</sub>				480	s

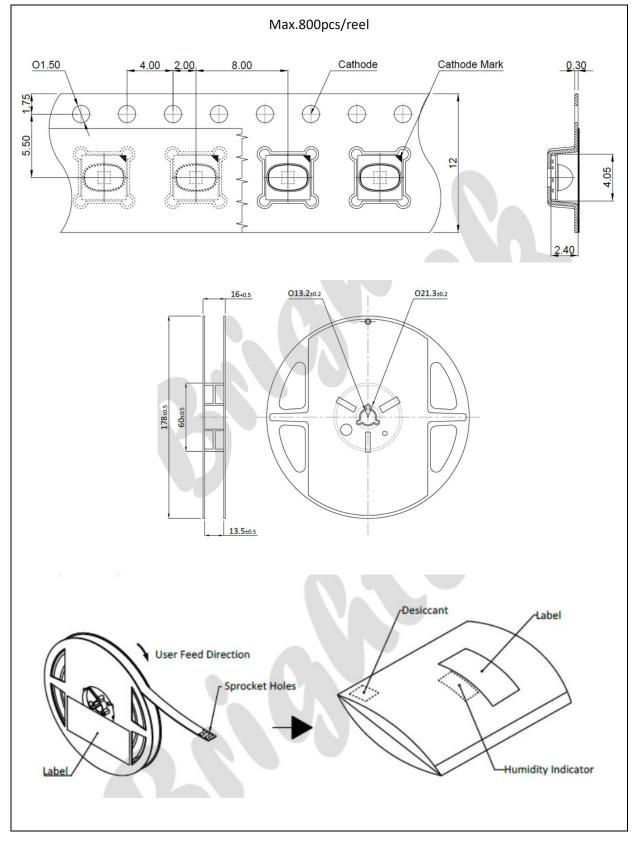
Note:

- 1. Maximum reflow soldering: 2 times.
- 2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



# **PACKING SPECIFICATION:**

#### **Reel Dimension:**



## **PRECAUTIONS OF USE:**



#### Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

#### Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

#### **Testing Circuit:**



Must apply resistor(s) for protection (over current proof).

#### Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

#### ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.



# **REVISION RECORD:**

Version	Date	Summary of Revision	
A1.0	22/05/2022	Datasheet set-up.	
A1.1	04/09/2024	Add packing and binning information.	